

## High voltage fast-switching NPN power transistor

#### **Features**

- High voltage capability
- Low spread of dynamic parameters
- Very high switching speed
- Integrated antiparallel collector-emitter diode

### **Applications**

- Electronic ballast for fluorescent lighting
- Flyback and forward single transistor low power converters

#### **Description**

These devices are high voltage fast-switching NPN power transistors. They are manufactured using high voltage multi epitaxial planar technology for high switching speeds and medium voltage capability.

They use a cellular emitter structure with planar edge termination to enhance switching speeds while maintaining the wide RBSOA. The devices are designed for use in lighting applications and low cost switch-mode power supplies.

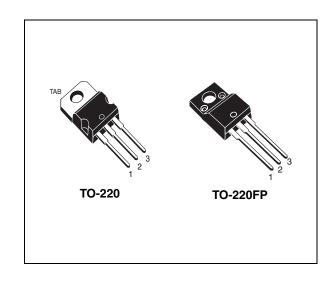


Figure 1. Internal schematic diagram

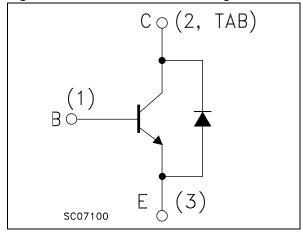


Table 1. Device summary

Order codes	Marking	Packages	Packaging
STL128D	L128D	TO-220	Tube
STL128DFP	L128DFP	TO-220FP	Tube

Content STL128D

## Content

1	Electrical ratings	3
2	Electrical characteristics	4
	2.1 Electrical characteristics (curves)	5
3	Package mechanical data	7
4	Revision history	11

STL128D Electrical ratings

# 1 Electrical ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value		Unit	
Symbol	Farameter	TO-220	TO-220FP	Oill	
V <sub>CES</sub>	Collector-emitter voltage (V <sub>BE</sub> = 0) 700		V		
V <sub>CEO</sub>	Collector-emitter voltage (I <sub>B</sub> = 0)	40	00	V	
V <sub>EBO</sub>	Emitter-base voltage ( $I_C = 0$ )	V <sub>(BF</sub>	R)EBO	V	
I <sub>C</sub>	Collector current 4		Α		
I <sub>CM</sub>	Collector peak current (t <sub>P</sub> < 5 ms) 8		Α		
I <sub>B</sub>	Base current 2		Α		
I <sub>BM</sub>	Base peak current (t <sub>P</sub> < 5 ms) 4		Α		
V <sub>ISOL</sub>	Insulation withstand voltage (RMS) from all three leads to external heatsink		1500	V	
P <sub>TOT</sub>	Total dissipation at T <sub>c</sub> = 25 °C 65 30		30	W	
T <sub>stg</sub>	Storage temperature -65 to 150		°C		
T <sub>J</sub>	Max. operating junction temperature 150		°C		

Table 3. Thermal data

Symbol	Parameter	Value		Unit
	raiametei	TO-220	TO-220FP	Oilit
R <sub>thJ-case</sub>	Thermal resistance junction-case max	1.92	4.17	°C/W
R <sub>thJ-amb</sub>	Thermal resistance junction-ambient max 62.5		°C/W	

Electrical characteristics STL128D

## 2 Electrical characteristics

 $T_{case}$  = 25 °C unless otherwise specified

Table 4. Electrical characteristics

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
I <sub>CES</sub>	Collector cut-off current (V <sub>BE</sub> = 0)	V <sub>CE</sub> = 700 V V <sub>CE</sub> = 700 V	T <sub>c</sub> = 125 °C			100 500	μ <b>Α</b> μ <b>Α</b>
I <sub>CEO</sub>	Collector cut-off current (I <sub>B</sub> = 0)	V <sub>CE</sub> = 400 V				250	μА
V <sub>(BR)EBO</sub>	Emitter-base breakdown voltage (I <sub>C</sub> = 0)	I <sub>E</sub> = 10 mA		9		18	V
V <sub>CEO(sus)</sub> <sup>(1)</sup>	Collector-emitter sustaining voltage (I <sub>B</sub> = 0)	I <sub>C</sub> = 100 mA		400			V
V <sub>CE(sat)</sub> <sup>(1)</sup>	Collector-emitter saturation voltage	$I_C = 1 A$ $I_C = 2.5 A$ $I_C = 3.5 A$	$I_B = 0.2 A$ $I_B = 0.5 A$ $I_B = 0.7 A$		0.5	1 1.5	V V V
V <sub>BE(sat)</sub> <sup>(1)</sup>	Base-emitter saturation voltage	I <sub>C</sub> = 1 A I <sub>C</sub> = 2.5 A	$I_B = 0.2 A$ $I_B = 0.5 A$			1.2 1.3	V V
h <sub>FE</sub> <sup>(1)</sup>	DC current gain	$I_C = 10 \text{ mA}$ $I_C = 2 \text{ A}$	$V_{CE} = 5 V$ $V_{CE} = 5 V$	10 10		32	
t <sub>s</sub>	Inductive load Storage time Fall time	$V_{CC} = 200 \text{ V}$ $I_{B1} = 0.4 \text{ A}$ $R_{BB} = 0$	I <sub>C</sub> =2 A V <sub>BE(off)</sub> = - 5 V L = 200 μH		0.6 0.1		μs μs

<sup>1.</sup> Pulse test: pulse duration  $\leq$  300  $\mu$ s, duty cycle  $\leq$  1.5 %.

## 2.1 Electrical characteristics (curves)

Figure 2. Safe operating area

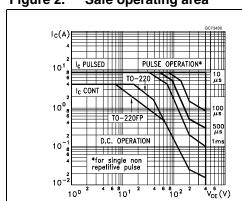


Figure 3. Derating curve

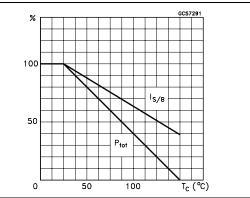
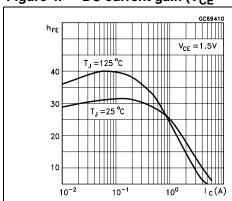


Figure 4. DC current gain ( $V_{CE} = 1.5 \text{ V}$ ) Figure 5. DC current gain ( $V_{CE} = 5 \text{ V}$ )



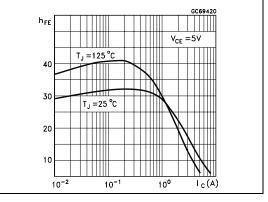
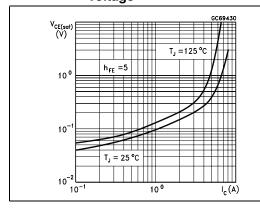
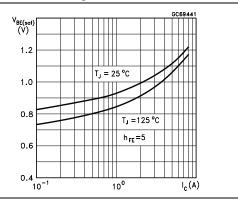


Figure 6. Collector-emitter saturation voltage

Figure 7. Base-emitter saturation voltage

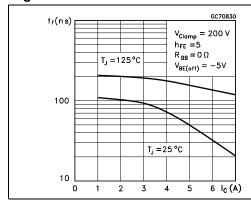




Electrical characteristics STL128D

Figure 8. Inductive load fall time

Figure 9. Inductive load storage time



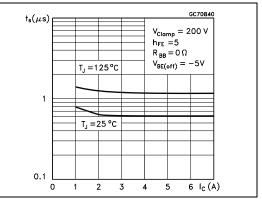
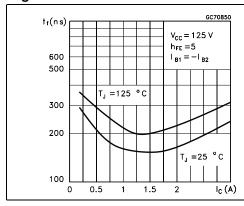


Figure 10. Resistive load fall time

Figure 11. Resistive load storage time



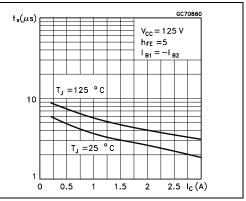
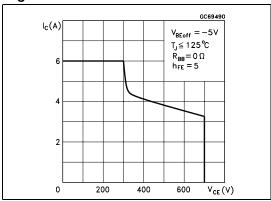


Figure 12. Reverse biased SOA



## 3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.

Table 5. TO-220 type A mechanical data

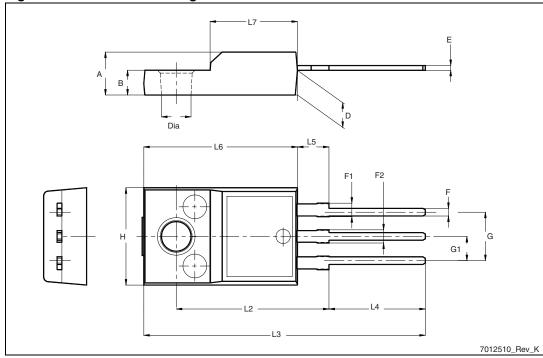
Dim.	mm				
	Min.	Тур.	Max.		
А	4.40		4.60		
b	0.61		0.88		
b1	1.14		1.70		
С	0.48		0.70		
D	15.25		15.75		
D1		1.27			
E	10		10.40		
е	2.40		2.70		
e1	4.95		5.15		
F	1.23		1.32		
H1	6.20		6.60		
J1	2.40		2.72		
L	13		14		
L1	3.50		3.93		
L20		16.40			
L30		28.90			
ØP	3.75		3.85		
Q	2.65		2.95		

Figure 13. TO-220 type A drawing

Table 6. TO-220FP mechanical data

Dim	mm.				
Dim.	Min.	Тур.	Max.		
Α	4.4		4.6		
В	2.5		2.7		
D	2.5		2.75		
E	0.45		0.7		
F	0.75		1		
F1	1.15		1.70		
F2	1.15		1.70		
G	4.95		5.2		
G1	2.4		2.7		
Н	10		10.4		
L2		16			
L3	28.6		30.6		
L4	9.8		10.6		
L5	2.9		3.6		
L6	15.9		16.4		
L7	9		9.3		
Dia	3		3.2		

Figure 14. TO-220FP drawing



STL128D Revision history

# 4 Revision history

Table 7. Document revision history

Date	Revision	Changes
27-Jun-2011	1	First release

#### Please Read Carefully:

Information in this document is provided solely in connection with ST products. STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, modifications or improvements, to this document, and the products and services described herein at any time, without notice.

All ST products are sold pursuant to ST's terms and conditions of sale.

Purchasers are solely responsible for the choice, selection and use of the ST products and services described herein, and ST assumes no liability whatsoever relating to the choice, selection or use of the ST products and services described herein.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted under this document. If any part of this document refers to any third party products or services it shall not be deemed a license grant by ST for the use of such third party products or services, or any intellectual property contained therein or considered as a warranty covering the use in any manner whatsoever of such third party products or services or any intellectual property contained therein.

UNLESS OTHERWISE SET FORTH IN ST'S TERMS AND CONDITIONS OF SALE ST DISCLAIMS ANY EXPRESS OR IMPLIED WARRANTY WITH RESPECT TO THE USE AND/OR SALE OF ST PRODUCTS INCLUDING WITHOUT LIMITATION IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION), OR INFRINGEMENT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT.

UNLESS EXPRESSLY APPROVED IN WRITING BY AN AUTHORIZED ST REPRESENTATIVE, ST PRODUCTS ARE NOT RECOMMENDED, AUTHORIZED OR WARRANTED FOR USE IN MILITARY, AIR CRAFT, SPACE, LIFE SAVING, OR LIFE SUSTAINING APPLICATIONS, NOR IN PRODUCTS OR SYSTEMS WHERE FAILURE OR MALFUNCTION MAY RESULT IN PERSONAL INJURY, DEATH, OR SEVERE PROPERTY OR ENVIRONMENTAL DAMAGE. ST PRODUCTS WHICH ARE NOT SPECIFIED AS "AUTOMOTIVE GRADE" MAY ONLY BE USED IN AUTOMOTIVE APPLICATIONS AT USER'S OWN RISK.

Resale of ST products with provisions different from the statements and/or technical features set forth in this document shall immediately void any warranty granted by ST for the ST product or service described herein and shall not create or extend in any manner whatsoever, any liability of ST.

ST and the ST logo are trademarks or registered trademarks of ST in various countries.

Information in this document supersedes and replaces all information previously supplied.

The ST logo is a registered trademark of STMicroelectronics. All other names are the property of their respective owners.

© 2011 STMicroelectronics - All rights reserved

STMicroelectronics group of companies

Australia - Belgium - Brazil - Canada - China - Czech Republic - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan -Malaysia - Malta - Morocco - Philippines - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States of America

www.st.com

12/12 Doc ID 018977 Rev 1



## **X-ON Electronics**

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Bipolar Transistors - BJT category:

Click to view products by STMicroelectronics manufacturer:

Other Similar products are found below:

619691C MCH4017-TL-H BC546/116 BC556/FSC BC557/116 BSW67A HN7G01FU-A(T5L,F,T NJVMJD148T4G

NSVMMBT6520LT1G NTE187A NTE195A NTE2302 NTE2330 NTE2353 NTE316 NTE65 C4460 SBC846BLT3G 2SA1419T
TD-H 2SA1721-O(TE85L,F) 2SA1727TLP 2SA2126-E 2SB1202T-TL-E 2SB1204S-TL-E 2SC5488A-TL-H 2SD2150T100R SP000011176

FMC5AT148 2N2369ADCSM 2SB1202S-TL-E 2SC2412KT146S 2SC4618TLN 2SC5490A-TL-H 2SD1816S-TL-E 2SD1816T-TL-E

CMXT2207 TR CPH6501-TL-E MCH4021-TL-E TTC012(Q) BULD128DT4 DDTC114EUAQ-7-F NJL0281DG NSS20500UW3TBG

732314D CMXT3906 TR CPH3121-TL-E CPH6021-TL-H SZT1010T1G 873787E